

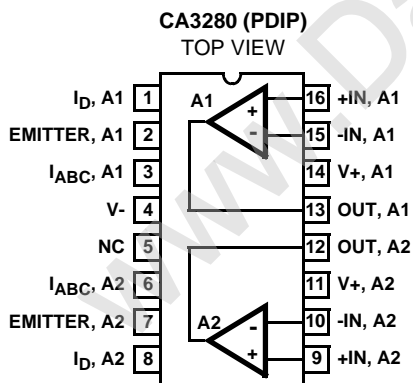
Dual, 9MHz, Operational Transconductance Amplifier (OTA)

The CA3280 and CA3280A types consist of two variable operational amplifiers that are designed to substantially reduce the initial input offset voltage and the offset voltage variation with respect to changes in programming current. This design results in reduced "AGC thump," an objectionable characteristic of many AGC systems. Interdigitation, or crosscoupling, of critical portions of the circuit reduces the amplifier dependence upon thermal and processing variables.

The CA3280 has all the generic characteristics of an operational voltage amplifier except that the forward transfer characteristics is best described by transconductance rather than voltage gain, and the output is current, not voltage. The magnitude of the output current is equal to the product of transconductance and the input voltage. This type of operational transconductance amplifier was first introduced in 1969, and it has since gained wide acceptance as a gateable, gain controlled building block for instrumentation and audio applications, such as linearization of transducer outputs, standardization of widely changing signals for data processing, multiplexing, instrumentation amplifiers operating from the nanopower range to high current and high speed comparators.

For additional application information on this device and on OTAs in general, please refer to Application Notes: AN6818, AN6668, and AN6077.

Pinout



Ordering Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE	PKG. NO.
CA3280AE	-55 to 125	16 Ld PDIP	E16.3
CA3280E	0 to 70	16 Ld PDIP	E16.3

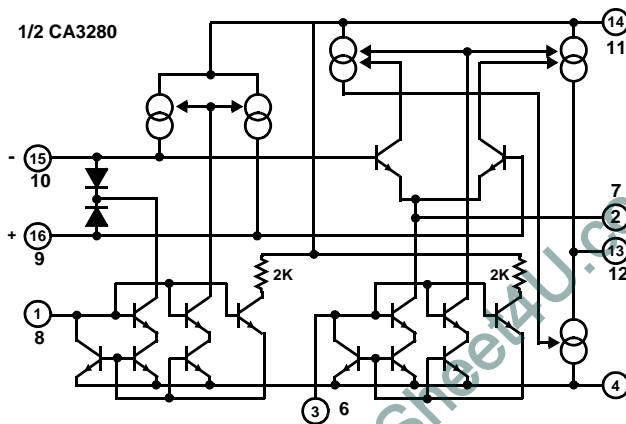
Features

- Low Initial Input Offset Voltage: 500 μ V (Max) (CA3280A)
- Low Offset Voltage Change vs I_{ABC} : <500 μ V (Typ) for All Types
- Low Offset Voltage Drift: 5 μ V/°C (Max) (CA3280A)
- Excellent Matching of the Two Amplifiers for All Characteristics
- Internal Current-Driven Linearizing Diodes Reduce the External Input Current to an Offset Component
- Flexible Supply Voltage Range \pm 2V to \pm 15V

Applications

- Voltage Controlled Amplifiers
- Voltage Controlled Oscillators
- Multipliers
- Demodulators
- Sample and Hold
- Instrumentation Amplifiers
- Function Generators
- Triangle Wave-to-Sine Wave Converters
- Comparators
- Audio Preamplifier

Functional Diagram



CA3280, CA3280A

Absolute Maximum Ratings

Supply Voltage (Between V+ and V-)	+36V
Differential Input Voltage	5V
Input Voltage Range	V+ to V-
Input Current at $I_D = 0$	100 μ A
Amplifier Bias Current (I_{ABC})	10mA
Output Short Circuit Duration (Note 2)	Indefinite
Linearizing Diode Bias Current, I_D	5mA
Peak Input Current with Linearizing Diode	$\pm I_D$

Thermal Information

Thermal Resistance (Typical, Note 1)	θ_{JA} ($^{\circ}$ C/W)	θ_{JC} ($^{\circ}$ C/W)
PDIP Package	90	N/A
Maximum Junction Temperature (Plastic Package)	150 $^{\circ}$ C	
Maximum Storage Temperature Range	-65 $^{\circ}$ C to 150 $^{\circ}$ C	
Maximum Lead Temperature (Soldering 10s)	300 $^{\circ}$ C	

Operating Conditions

Temperature Range	
CA3280	0 $^{\circ}$ C to 70 $^{\circ}$ C
CA3280A	-55 $^{\circ}$ C to 125 $^{\circ}$ C
Supply Voltage Range (Typ)	± 2 V to ± 15 V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

- θ_{JA} is measured with the component mounted on a low effective thermal conductivity test board in free air. See Tech Brief TB379 for details.
- Short circuit may be applied to ground or to either supply.

Electrical Specifications For Equipment Design, at $T_A = 25^{\circ}$ C, $V_{SUPPLY} = \pm 15$ V, Unless Otherwise Specified

PARAMETER	SYMBOL	TEST CONDITIONS	CA3280			CA3280A			UNITS	
			MIN	TYP	MAX	MIN	TYP	MAX		
Input Offset Voltage	V_{IO}	$I_{ABC} = 1\text{mA}$	-	-	3	-	-	0.5	mV	
		$I_{ABC} = 100\mu\text{A}$	-	0.7	3	-	0.25	0.5	mV	
		$I_{ABC} = 10\mu\text{A}$	-	-	3	-	-	0.5	mV	
		$I_{ABC} = 1\text{mA to } 10\mu\text{A}$, $T_A = \text{Full Temp. Range}$	-	0.8	4	-	0.8	1.5	mV	
Input Offset Voltage Drift	$ \Delta V_{IO} $	$I_{ABC} = 1\mu\text{A to } 1\text{mA}$	-	0.5	1	-	0.5	1	mV	
		$I_{ABC} = 100\mu\text{A}$, $T_A = \text{Full Temperature Range}$	-	5	-	-	3	5	$\mu\text{V}/^{\circ}\text{C}$	
Amplifier Bias Voltage	V_{ABC}	$I_{ABC} = 100\mu\text{A}$	-	1.2	-	-	1.2	-	V	
Peak Output Voltage	V_{OM+}	$I_{ABC} = 500\mu\text{A}$	12	13.7	-	12.5	13.7	-	V	
	V_{OM-}		12	-14.3	-	-13.3	-14.3	-	V	
	V_{OM+}	$I_{ABC} = 5\mu\text{A}$	12	13.9	-	12.5	13.9	-	V	
	V_{OM-}		12	-14.5	-	-13.5	-14.5	-	V	
Common Mode Input Voltage Range	V_{ICR}	$I_{ABC} = 100\mu\text{A}$	-13	-	13	-13	-	13	V	
Noise Voltage	e_N	$I_{ABC} = 500\mu\text{A}$	10Hz	-	20	-	-	20	-	$\text{nV}/\sqrt{\text{Hz}}$
			1kHz	-	8	-	-	8	-	$\text{nV}/\sqrt{\text{Hz}}$
			10kHz	-	7	-	-	7	-	$\text{nV}/\sqrt{\text{Hz}}$
Input Offset Current	I_{IO}	$I_{ABC} = 500\mu\text{A}$	-Z	0.3	0.7	-	0.3	0.7	μA	
Input Bias Current	I_{IB}	$I_{ABC} = 500\mu\text{A}$	-	1.8	5	-	1.8	5	μA	
		$I_{ABC} = 500\mu\text{A}$, $T_A = \text{Full Temperature Range}$	-	3	8	-	3	8	μA	

CA3280, CA3280A

Electrical Specifications For Equipment Design, at $T_A = 25^\circ\text{C}$, $V_{\text{SUPPLY}} = \pm 15\text{V}$, Unless Otherwise Specified (Continued)

PARAMETER	SYMBOL	TEST CONDITIONS		CA3280			CA3280A			UNITS
				MIN	TYP	MAX	MIN	TYP	MAX	
Peak Output Current	$I_{\text{OM}+}$	$I_{\text{ABC}} = 500\mu\text{A}$	Source	350	410	650	350	410	650	μA
	$I_{\text{OM}-}$		Sink	-350	-410	-650	-350	-410	-650	μA
	$I_{\text{OM}+}$	$I_{\text{ABC}} = 5\mu\text{A}$	Source	3	4.1	7	3	4.1	7	μA
	$I_{\text{OM}-}$		Sink	-3	-4.1	-7	-3	-4.1	-7	μA
Peak Output Current Sink and Source	$I_{\text{OM}-}$, $I_{\text{OM}+}$	$I_{\text{ABC}} = 500\mu\text{A}$, $T_A = \text{Full Temperature Range}$		350	450	550	350	450	550	μA
Linearization Diodes	Offset Current Dynamic Impedance	$I_D = 100\mu\text{A}$		-	10	-	-	10	-	μA
		$I_D = 10\mu\text{A}$		-	0.5	1	-	0.5	1	μA
		$I_D = 100\mu\text{A}$		-	700	-	-	700	-	Ω
Diode Network Supply Current		$I_{\text{ABC}} = 100\mu\text{A}$		250	400	800	250	400	800	μA
Amplifier Supply Current (Per Amplifier)	I_+	$I_{\text{ABC}} = 500\mu\text{A}$		-	2	2.4	-	2	2.4	mA
Amplifier Output Leakage Current	I_{OL}	$I_{\text{ABC}} = 0$, $V_O = 0\text{V}$		-	0.015	0.1	-	0.015	0.1	nA
		$I_{\text{ABC}} = 0$, $V_O = 30\text{V}$		-	0.15	1	-	0.15	1	nA
Common Mode Rejection Ratio	CMRR	$I_{\text{ABC}} = 100\mu\text{A}$		80	100	-	94	100	-	dB
Power Supply Rejection Ratio	PSRR	$I_{\text{ABC}} = 100\mu\text{A}$		86	105	-	94	105	-	dB
Open Loop Voltage Gain	A_{OL}	$I_{\text{ABC}} = 100\mu\text{A}$, $R_L = \infty$, $V_O = 20\text{V}_{\text{P-P}}$		94	100	-	94	100	-	dB
				50	100	-	50	100	-	kV/V
Forward Transconductance	G_M	$I_{\text{ABC}} = 50\mu\text{A}$, Large Signal		-	0.8	1.2	-	0.8	1.2	mS
	g_M	$I_{\text{ABC}} = 1\text{mA}$, Small Signal		-	16	22	-	16	22	mS
Input Resistance	R_I	$I_{\text{ABC}} = 10\mu\text{A}$		0.5	-	-	0.5	-	-	$\text{M}\Omega$
Channel Separation		$f = 1\text{kHz}$		-	94	-	-	94	-	dB
Open Loop Total Harmonic Distortion	THD	$f = 1\text{kHz}$, $I_{\text{ABC}} = 1.5\text{mA}$, $R_L = 15\text{k}\Omega$, $V_O = 20\text{V}_{\text{P-P}}$		-	0.4	-	-	0.4	-	$\%$
Bandwidth	f_T	$I_{\text{ABC}} = 1\text{mA}$, $R_L = 100\Omega$		-	9	-	-	9	-	MHz
Slew Rate, Open Loop	SR	$I_{\text{ABC}} = 1\text{mA}$		-	125	-	-	125	-	$\text{V}/\mu\text{s}$
Capacitance	C_I	$I_{\text{ABC}} = 100\mu\text{A}$	Input	-	4.5	-	-	4.5	-	pF
	C_O		Output	-	7.5	-	-	7.5	-	pF
Output Resistance	R_O	$I_{\text{ABC}} = 100\mu\text{A}$		-	63	-	-	63	-	$\text{M}\Omega$

Test Circuits and Waveforms

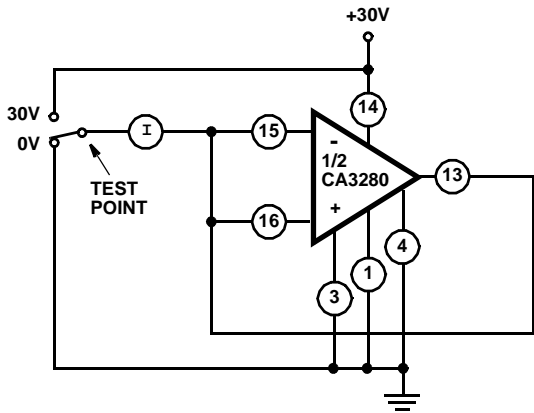


FIGURE 1. LEAKAGE CURRENT TEST CIRCUIT

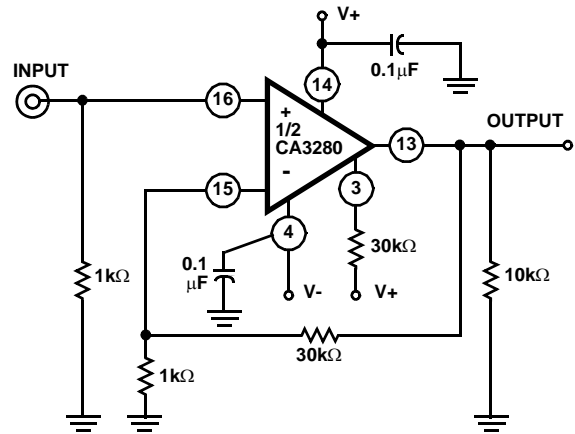
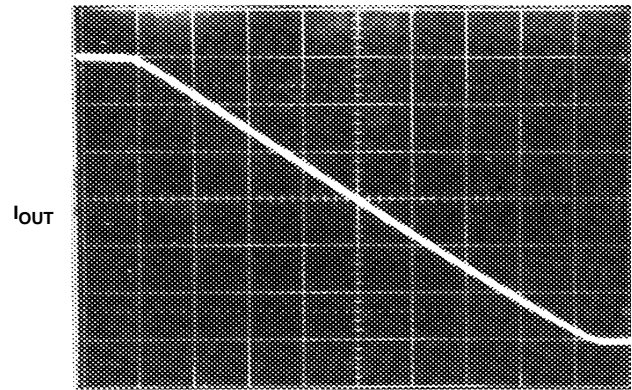
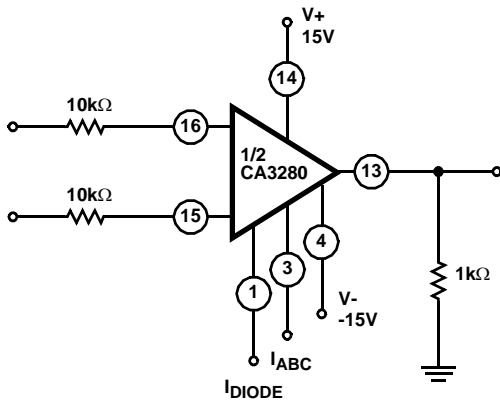
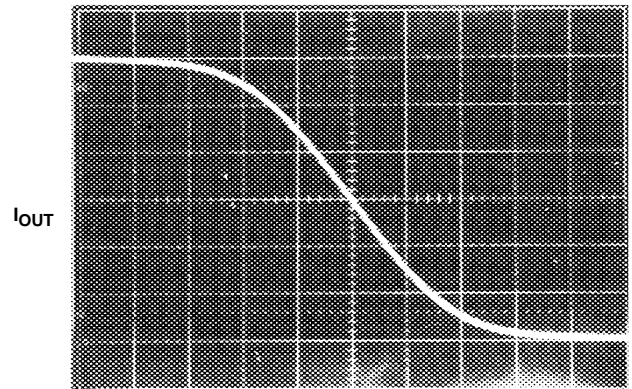
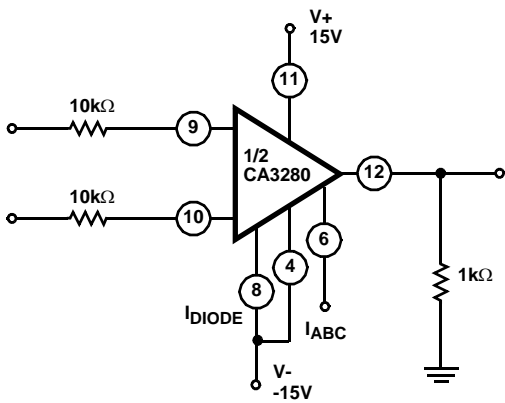


FIGURE 2. CHANNEL SEPARATION TEST CIRCUIT



$I_{ABC} = 650\mu A$, $I_D = 200\mu A$; Vertical = $200\mu A/Div.$; Horizontal = $1V/Div.$

FIGURE 3A. EFFECTS OF DIODE LINEARIZATION, WITH DIODE PROGRAMMING TERMINAL ACTIVE



$I_{ABC} = 650\mu A$, $I_D = 0$; Vertical = $200\mu A/Div.$; Horizontal = $25mV/Div.$

FIGURE 3B. WITH DIODE PROGRAMMING TERMINAL CUTOFF

FIGURE 3. CA3280 TRANSFER CHARACTERISTICS

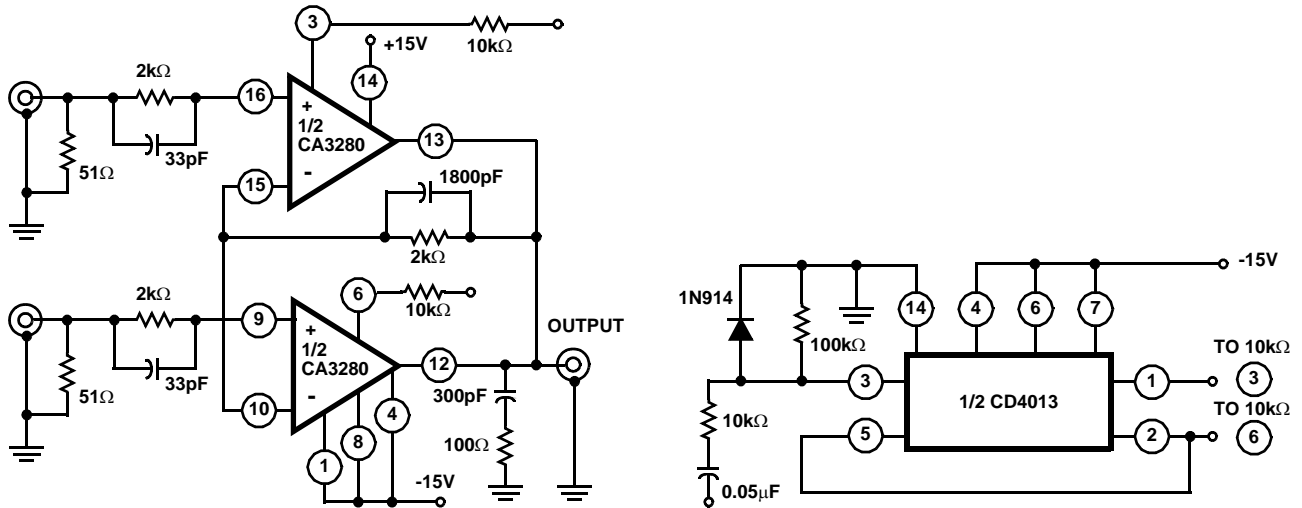


FIGURE 8. TWO CHANNEL LINEAR MULTIPLEXER

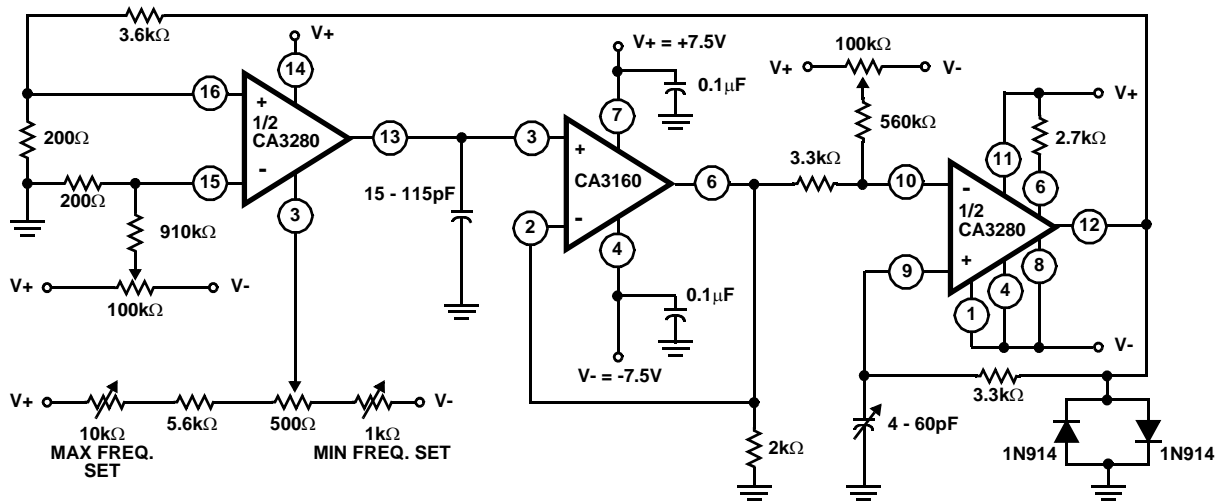


FIGURE 9. CA3280 USED IN CONJUNCTION WITH A CA3160 TO PROVIDE A FUNCTION GENERATOR WITH A TUNABLE RANGE OF 2Hz TO 1MHz

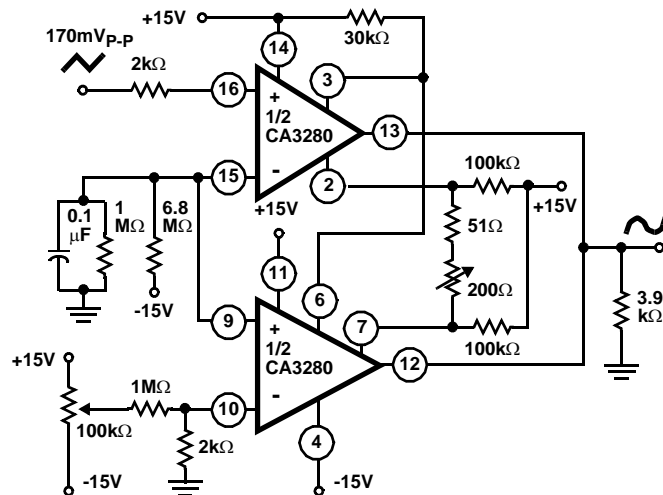


FIGURE 10. TRIANGLE WAVE-TO-SINE WAVE CONVERTER

Typical Performance Curves

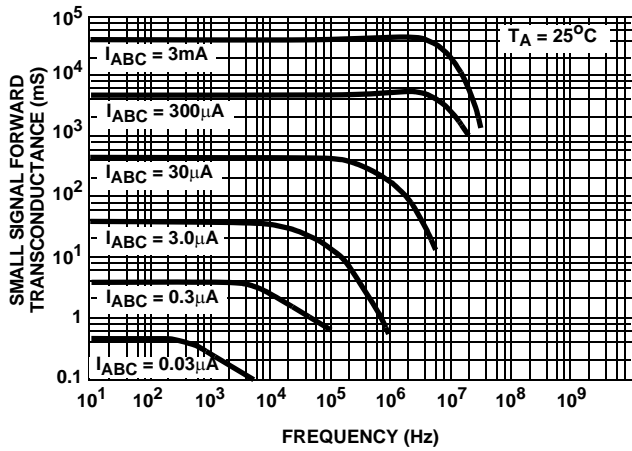


FIGURE 11. AMPLIFIER GAIN vs FREQUENCY

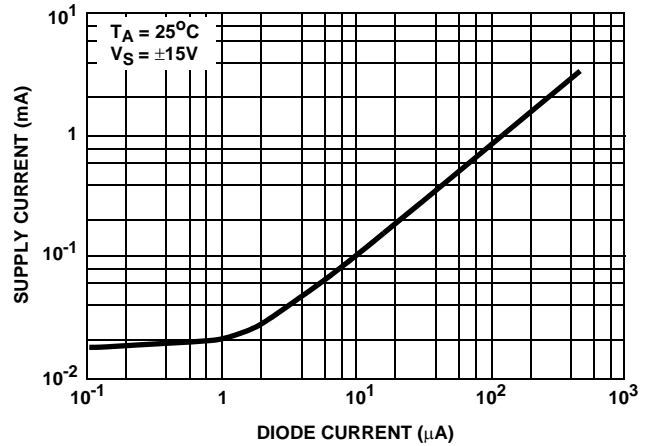


FIGURE 12. SUPPLY CURRENT vs DIODE CURRENT

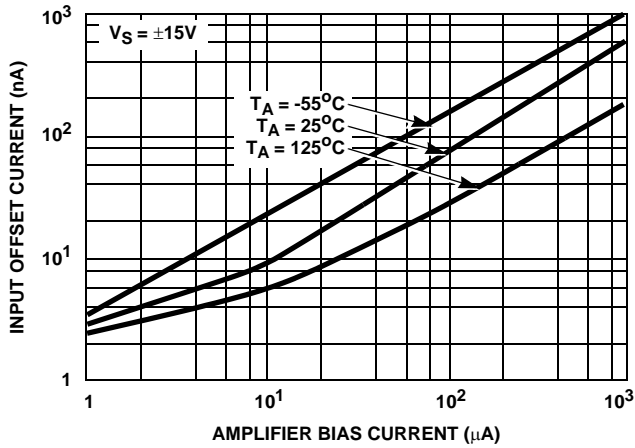


FIGURE 13. INPUT OFFSET CURRENT vs AMPLIFIER BIAS CURRENT

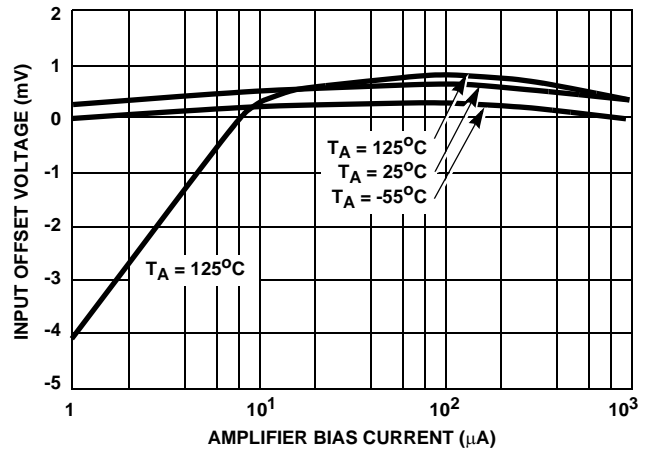


FIGURE 14. INPUT OFFSET VOLTAGE vs AMPLIFIER BIAS CURRENT

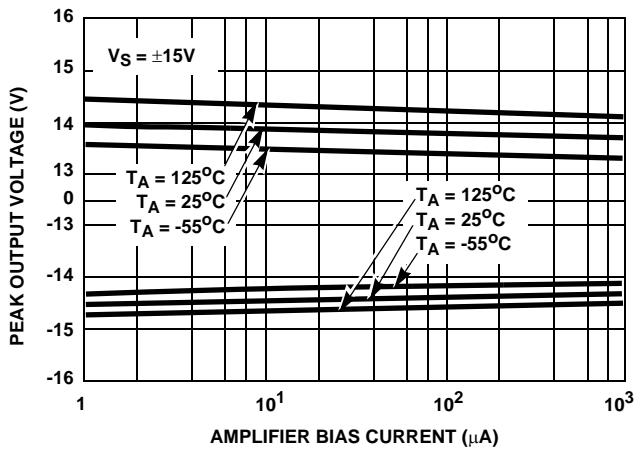


FIGURE 15. PEAK OUTPUT VOLTAGE vs AMPLIFIER BIAS CURRENT

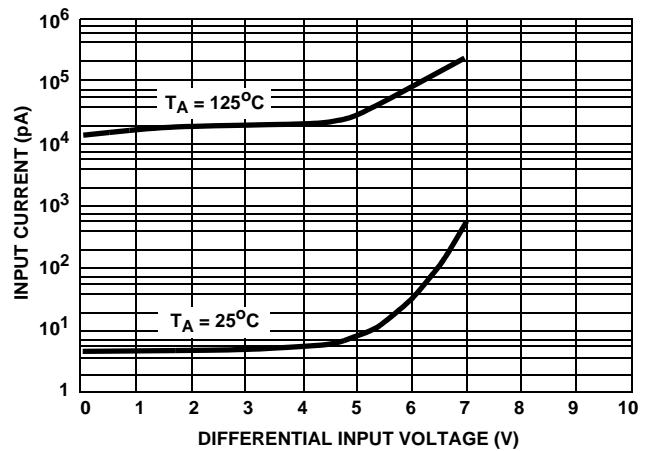


FIGURE 16. INPUT CURRENT vs INPUT DIFFERENTIAL VOLTAGE

Typical Performance Curves (Continued)

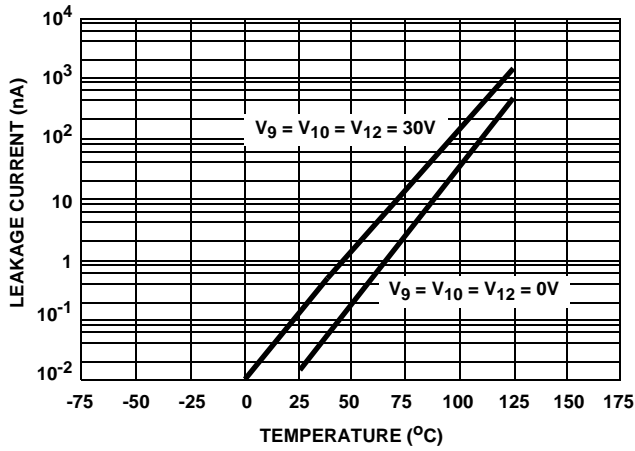


FIGURE 17. LEAKAGE CURRENT vs TEMPERATURE

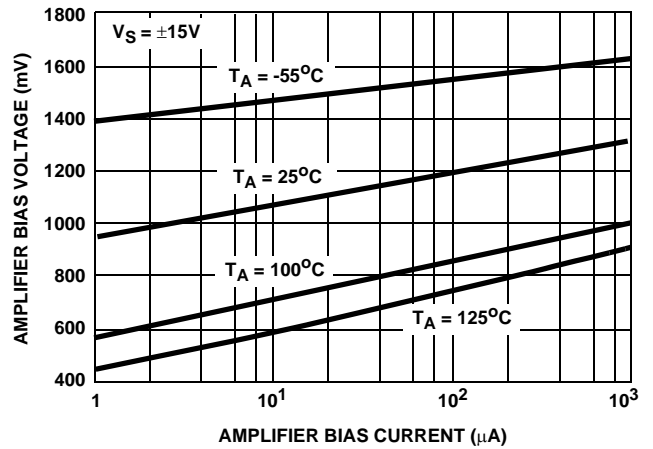


FIGURE 18. AMPLIFIER BIAS VOLTAGE vs AMPLIFIER BIAS CURRENT

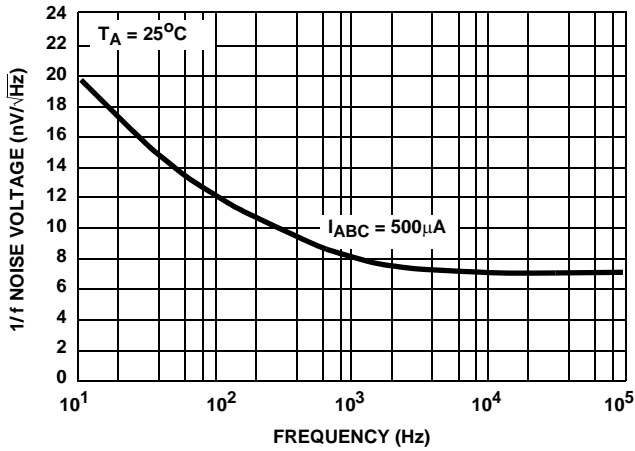


FIGURE 19. 1/f NOISE vs FREQUENCY

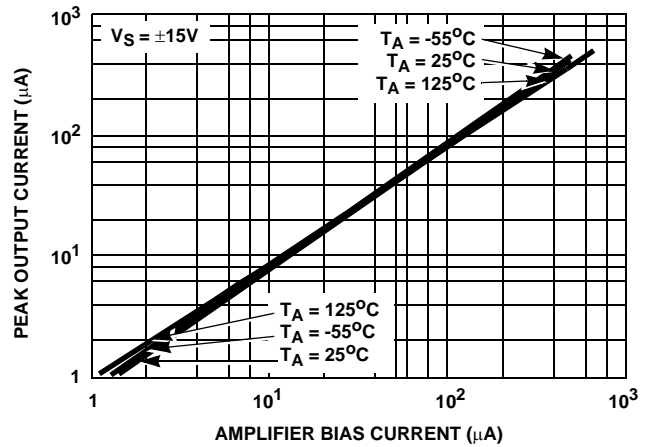


FIGURE 20. PEAK OUTPUT CURRENT vs AMPLIFIER BIAS CURRENT

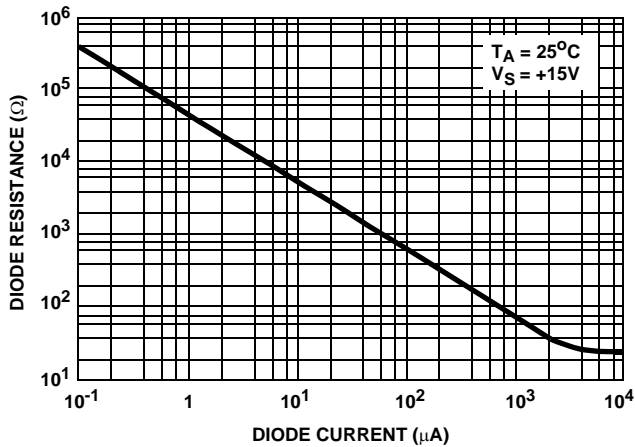


FIGURE 21. DIODE RESISTANCE vs DIODE CURRENT

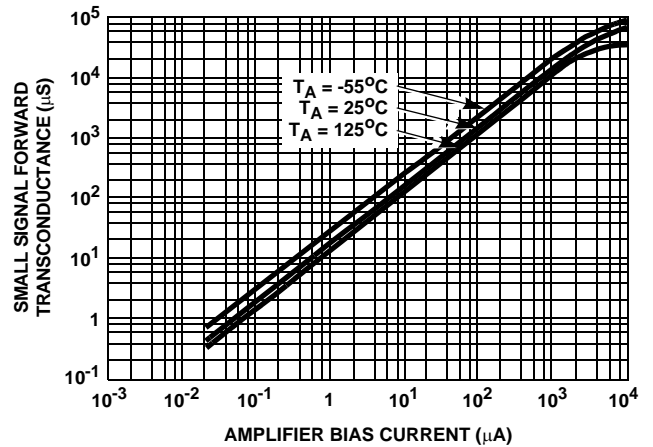


FIGURE 22. AMPLIFIER GAIN vs AMPLIFIER BIAS CURRENT

Typical Performance Curves (Continued)

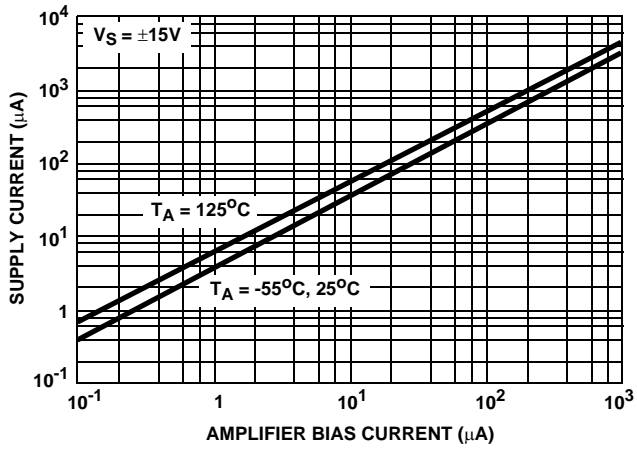


FIGURE 23. SUPPLY CURRENT vs AMPLIFIER BIAS CURRENT

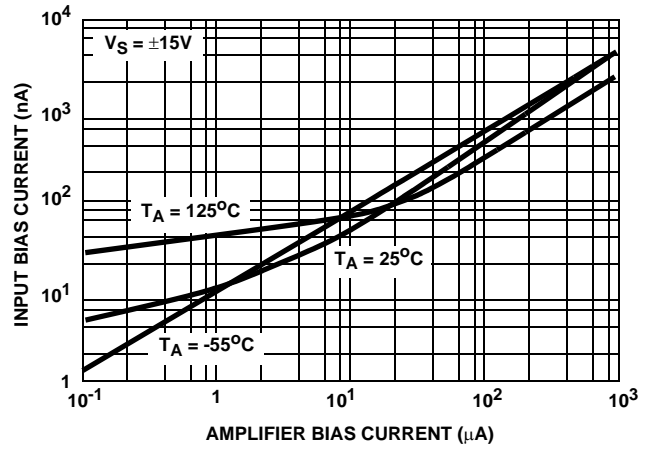
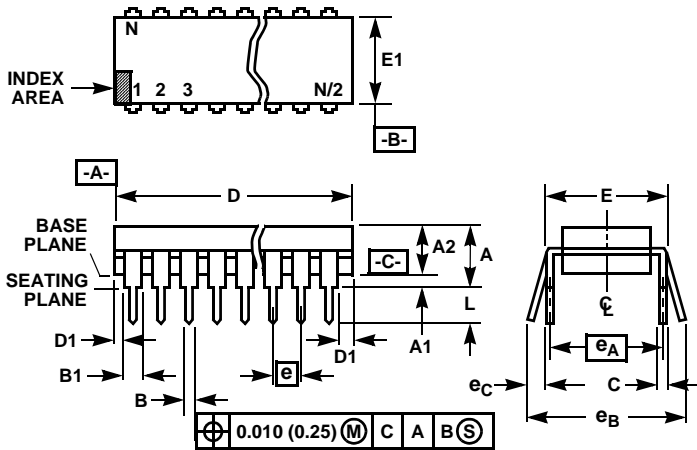


FIGURE 24. INPUT BIAS CURRENT vs AMPLIFIER BIAS CURRENT

Dual-In-Line Plastic Packages (PDIP)



NOTES:

- Controlling Dimensions: INCH. In case of conflict between English and Metric dimensions, the inch dimensions control.
- Dimensioning and tolerancing per ANSI Y14.5M-1982.
- Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication No. 95.
- Dimensions A, A1 and L are measured with the package seated in JEDEC seating plane gauge GS-3.
- D, D1, and E1 dimensions do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.010 inch (0.25mm).
- E and e_A are measured with the leads constrained to be perpendicular to datum $-C-$.
- e_B and e_C are measured at the lead tips with the leads unconstrained. e_C must be zero or greater.
- B1 maximum dimensions do not include dambar protrusions. Dambar protrusions shall not exceed 0.010 inch (0.25mm).
- N is the maximum number of terminal positions.
- Corner leads (1, N, N/2 and N/2 + 1) for E8.3, E16.3, E18.3, E28.3, E42.6 will have a B1 dimension of 0.030 - 0.045 inch (0.76 - 1.14mm).

E16.3 (JEDEC MS-001-BB ISSUE D)
16 LEAD DUAL-IN-LINE PLASTIC PACKAGE

SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN	MAX	MIN	MAX	
A	-	0.210	-	5.33	4
A1	0.015	-	0.39	-	4
A2	0.115	0.195	2.93	4.95	-
B	0.014	0.022	0.356	0.558	-
B1	0.045	0.070	1.15	1.77	8, 10
C	0.008	0.014	0.204	0.355	-
D	0.735	0.775	18.66	19.68	5
D1	0.005	-	0.13	-	5
E	0.300	0.325	7.62	8.25	6
E1	0.240	0.280	6.10	7.11	5
e	0.100 BSC		2.54 BSC		-
e_A	0.300 BSC		7.62 BSC		6
e_B	-	0.430	-	10.92	7
L	0.115	0.150	2.93	3.81	4
N	16		16		9

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